

10-16-03

FORM PTO-1449 (Modified [6-1]) LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT(S)' INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)	ATTY. DOCKET NO.: 2022027-7035362001	SERIAL NO.: NEW APPLICATION
	INVENTOR(s): Charles E. Hamilton, et al.	
	FILING DATE: HEREWITH	GROUP ART UNIT: UNKNOWN

REFERENCE DESIGNATION		U.S. PATENT DOCUMENTS					
EXAM'R INITIAL		DOCUMENT NUMBER	DATE	NAME	Class	Subclass	Filing Date If Appropriate
JW	A1	6,192,062	01/20/01	Sanchez-Rubio, et al.	372	92	02/04/00

OTHER ART (Include Author, Title, Date, Pertinent Pages, etc.)

JW	C1	Ming-Wei Pan, et al., "Fiber-coupled high-power external-cavity semiconductor lasers for real-time Raman sensing", Applied Optics, Vol. 37, No. 24, August 20, 1998.
	C2	Jean-Francois Lepage, et al., "Apodizing holographic gratings for the modal control of semiconductor lasers", Applied Optics, Vol. 36, No. 21, July 20, 1997.
	C3	Carlow R. Fernandez-Pousa, et al., "Talbot conditions, Talbot resonators, and first-order systems", J. Opt. Soc. AM. A, Vol. 20, No. 4, April 2003.
	C4	R.G. Waarts, et al. "Coherent Radiation from a broad area semiconductor laser in an external cavity", Laser-Diode Technology and Applications II, SPIE, Vol. 1219, (1990).
	C5	Sylvan Mailhot, et al. "Single-mode operation of a broad-area semiconductor laser with an anamorphic external cavity: experimental and numerical results" Applied Optics, Vol 39, No. 36, December 20, 2000.
	C6	Morris B. Snipes, Jr., et al. "Transverse mode filtering of wide stripe semiconductor lasers using an external cavity", SPIE Vol, 1634, Laser Diode Technology and Applications IV (1992).
	C7	A.C. Fey-den Boer, et al.. "Grating feedback in a 810 nm broad-area diode laser", Applied Physics, B. 63, 117-120 (1996).
	C8	Sylvie Yiou, et al. "Improvement of the spatial beam quality of laser sources with an intracavity Bragg grating", Optics Letters, Vol. 28, No. 4, February 15, 2003.
	C9	W. Nagengast, et al., "High-power single-mode emission from a broad-area semiconductor laser with a pseudoexternal cavity and a Fabry-Perot etalon", Optics Letters, Vol. 22, No. 16, August 15, 1997.
	C10	Damien Stryckman, et al., "Improvement of the lateral-mode discrimination of broad-area diode lasers with a profiled reflectivity output facet", Applied Optics, Vol. 35, No. 30, October 20, 1996.
	C11	Takashige Omatsu, et al. "Longitudinal-single mode operation of broad-stripe laser diode using a photorefractive phase conjugator", SPIE, Vol. 2896 (1996)

EXAMINER: James Vannucci	DATE CONSIDERED: 12-8-05
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant(s).	